



SILENT SWITCHER 2

High Efficiency • High Frequency • Low EMI





LT8650S EMI/EMC Curve 5V@3.8A, 3.3V@4.2V, f_{SW} = 2MHz with Spread Spectrum

| Part Number | Silent Switcher Family | V _{IN} Range (V) | I _{OUT} (A) | V _{OUT(MIN)} (V) | Frequency | Ι _Q (μΑ) | Package |
|------------------------|------------------------|---------------------------|----------------------|---------------------------|------------------|---------------------|------------------|
| 65V _{IN(MAX)} | | | | | | | |
| LT8641 | Silent Switcher | 3.0 to 65 | 3.5 | 0.8 | 200kHz to 3MHz | 2.5 | 3x4 QFN-18 |
| LT8645S | Silent Switcher 2 | 3.4 to 65 | 8 | 0.8 | 200kHz to 2.2MHz | 2.5 | 4x6 LQFN-32 |
| 42VIN(MAX) | | | | | | | |
| LT8606 | Low EMI | 3.0 to 42 | 350mA | 0.8 | 200kHz to 2.2MHz | 3 | 2x2 DFN, MSOP10E |
| LT8607 | Low EMI | 3.0 to 42 | 750mA | 0.8 | 200kHz to 2.2MHz | 3 | 2x2 DFN, MSOP10E |
| LT8608 | Low EMI | 3.0 to 42 | 1.5 | 0.8 | 200kHz to 2.2MHz | 2.5 | 2x2 DFN, MSOP10E |
| LT8609S | Silent Switcher 2 | 3.0 to 42 | 2/3 Peak | 0.8 | 200kHz to 2.2MHz | 2.5 | 3x3 LQFN-16 |
| LT8609A | Low EMI | 3.0 to 42 | 2/3 Peak | 0.8 | 200kHz to 2.2MHz | 2.5 | 3x3 DFN, MSOP10E |
| LT8614 | Silent Switcher | 3.4 to 42 | 4 | 0.97 | 200kHz to 2.2MHz | 2.5 | 3x4 QFN-18 |
| LT8653S | Silent Switcher 2 | 3.0 to 42 | 2x2/3 Peak | 0.8 | 200kHz to 3MHz | 6 | 3x4 LQFN-20 |
| LT8640/-1 | Silent Switcher | 3.4 to 42 | 5/7 Peak | 0.97 | 200kHz to 3MHz | 2.5 | 3x4 QFN-18 |
| LT8640S | Silent Switcher 2 | 3.4 to 42 | 5/7 Peak | 0.97 | 200kHz to 3MHz | 2.5 | 4x4 LQFN-24 |
| LT8643S | Silent Switcher 2 | 3.4 to 42 | 5/7 Peak | 0.97 | 200kHz to 3MHz | 230 | 4x4 LQFN-24 |
| LT8650S | Silent Switcher 2 | 3.0 to 42 | 2x4/6 Peak | 0.8 | 200kHz to 3MHz | 6.2 | 4x6 LQFN-32 |
| LT8648S | Silent Switcher 2 | 3.0 to 42 | 15 | 0.6 | 200kHz to 3MHz | 6 | 4x7 LQFN-36 |
| 18V _{IN(MAX)} | | | | | | | |
| LT8642S | Silent Switcher 2 | 2.8 to 18 | 10 | 0.6 | 200kHz to 3MHz | 240 | 4x4 LQFN-24 |
| LTC7151S | Silent Switcher 2 | 3.1 to 20 | 15 | 0.6 | 400kHz to 3MHz | 2mA | 4x5 LQFN-28 |
| LTC7150S | Silent Switcher 2 | 3.1 to 20 | 20 | 0.6 | 400kHz to 3MHz | 2mA | 5x6 BGA-42 |
| LT8652S | Silent Switcher 2 | 3.0 to 18 | 8+8 | 0.6 | 300kHz to 3MHz | 6 | 4x7 LQFN-36 |
| 5VIN(MAX) | | | | | | | |
| LTC3307/8/9 | Silent Switcher | 2.25 to 5.5 | 3/4/6 | 0.5 | 500kHz to 5MHz | 45 | 2x2 LQFN-12 |
| LTC3315 | Silent Switcher | 2.25 to 5.5 | 2+2 | 0.5 | 500kHz to 5MHz | 70 | 2x2 LQFN-12 |
| LTC3310S | Silent Switcher 2 | 2.25 to 5.5 | 10 | 0.5 | 500kHz to 5MHz | 1.3mA | 3x3 LQFN-18 |
| LT8647S | Silent Switcher 2 | 2.8 to 8 | 7 | 0.6 | 300kHz to 4MHz | 140 | 3x4 LQFN-20 |
| LT8644S | Silent Switcher 2 | 2.8 to 8 | 15 | 0.6 | 300kHz to 4MHz | 145 | 4x4 LQFN-24 |



Silent Switcher 2 Unrivaled Ease-of-Use Faster • Smaller • Quieter

The LT8650S combines high efficiency at high frequencies and an ultralow EMI design to deliver a very compact dual output 4A (6A peak) synchronous step-down solution. It delivers efficiency as high as 94.4% (12VIN to 5VOLT) with a switching frequency of 2MHz offering a very compact solution footprint. The LT8650S's unique Silent Switcher®2 architecture uses four internal input capacitors as well as internal BST and INTV_{CC} capacitors to minimize the area of the hot loops. Additionally, its fast, clean, low overshoot switching edges enable both high efficiency operation, at high switching frequencies, and low EMI/EMC emissions. The internal construction uses copper pillars in lieu of bond wires and an integrated ground plane to further reduce EMI/EMC emissions. This improved EMI/EMC performance is not sensitive to PCB layout, simplifying design and reducing risk even when using two layer PC boards. The LT8650S can easily pass the automotive CISPR 25, Class 5 peak EMI limits with a 2MHz switching frequency over its entire load range. Spread spectrum frequency modulation is also available to further lower EMI/EMC levels.

- 4A from Each Channel Simultaneously
- Up to 6A on Either Channel
- Silent Switcher Architecture:
 - Ultralow EMI/EMC Emissions on Any PCB
 - Eliminates PCB Lavout Sensitivity
 - Internal Bypass Capacitors Reduce Radiated EMI
 - Optional Spread Spectrum Modulation
- Wide Input Voltage Range: 3.0V to 42V

Germany

- 94.4% Efficiency at 2MHz
- Ultralow Quiescent Current Burst Mode[®] Operation:
 - 6.2µA I_O, Output Ripple<10mV_{P-P}
- Fast Minimum Switch-On Time: 40ns
- Adjustable and Synchronizable: 300kHz to 3MHz
- Output Soft-Start and Tracking
- Small Thermally Enhanced 4mm × 6mm 32-Pin LGA Package



LT8650S Demo Board (DC2407A)

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